

TechniAl Data Data Sheet N0001 Rev. B Automotive Qualified

3.0SMCJ SERIES SURFACE MOUNT TRANSIENT VOLTAGE SUPPRESSOR



Circuit Diagram



Features

- **Glass Passivated Die Construction**
- **3000W Peak Pulse Power Dissipation**
- 5.0V- 170V Standoff Voltage
- Uni- and Bi-Directional Versions Available
- **Excellent Clamping Apability**
- **Fast Response Time**
- Plastic Ase Material has UL Flammability **ClassifiAtion Rating 94V-O**
- "-A" is an AEC-Q101 gualified device
- This is a Pb Free Device
- All SMC Parts are Traceable to the Wafer Lot
- Additional testing An be offered upon request

MechaniAl Data

- Ase: SMC Low Profile Molded Plastic
- Terminals: Solder Plated , Solderable per MIL-STD 750, Method 2026
- Polarity: Athode Band or Athode Notch

Bipolar

Maximum Ratings and Thermal Characteristics@TA=25°C unless otherwise specified

Parameter	Symbol	Value	Units
Peak Pulse Power Dissipation on 10/1000us waveform (NOTE 1, 2, Fig.1)	P _{PPM}	3000	W
Peak Pulse Current of on 10/1000 us waveform (Note 1,Fig 3)	I _{PPM}	SEE TABLE 1	А
Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 2),(Note 3)	I _{FSM}	300	А
TypiAl Thermal Resistance Junction to Lead	$R_{\theta JL}$	15	°C/W
TypiAI Thermal Resistance Junction to Ambient	R _{θJA}	75	°C/W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 to 150	°C

1. Non-repetitive current pulse , per Fig. 3 and derated above $T_1 = 25^{\circ}C$ per Fig. 2. Notes:

2. Mounted on Copper Pad area of 0.8x0.8" (20x20mm) per Fig.5.

3. Measured on 8.3ms single half sine wave or equivalent square wave, duty cycle=4pulses per minute maximum.

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Electrial Characteristics@T_A=25°C unless otherwise specified

		MAR	/ICE KING DE	REVER SE STAND- OFF	BREAKD OWN VOLTAG	BREAKDO WN VOLTAGE	TEST CURR	MAXMU M CLAMPI NG	PEAK PULS E	REVE RSE LEAK	REVERSE LEAKAGE
UNI-POLAR	BI-POLAR	UNI	ві	VOLTA GE V _{RWM} (V)	E VBR (V) MIN. @I _T	VBR (V) MAX. @It	ENT IT(MA)	VOLTAG E @Ipp V _c (V)	CURR ENT IPP(A)	AGE @V _{RW} M I _R (uA)	@V _{RWM} T _J =150°C I _R (uA)
3.0SMCJ5.0A	3.0SMCJ5.0CA	HDE	IDE	5	6.4	7	10	9.2	326.1	800	2500
3.0SMCJ6.0A	3.0SMCJ6.0CA	HDG	IDG	6	6.67	7.37	10	10.3	291.3	800	2500
3.0SMCJ6.5A	3.0SMCJ6.5CA	HDK	IDK	6.5	7.22	7.98	10	11.2	267.9	500	1500
3.0SMCJ7.0A	3.0SMCJ7.0CA	HDM	IDM	7	7.78	8.6	10	12	250	200	500
3.0SMCJ7.5A	3.0SMCJ7.5CA	HDP	IDP	7.5	8.33	9.21	1	12.9	232.6	100	300
3.0SMCJ8.0A	3.0SMCJ8.0CA	HDR	IDR	8	8.89	9.83	1	13.6	220.6	50	300
3.0SMCJ8.5A	3.0SMCJ8.5CA	HDT	IDT	8.5	9.44	10.4	1	14.4	208.3	20	50
3.0SMCJ9.0A	3.0SMCJ9.0CA	HDV	IDV	9	10	11.1	1	15.4	194.8	10	50
3.0SMCJ10A	3.0SMCJ10CA	HDX	IDX	10	11.1	12.3	1	17	176.5	5	50
3.0SMCJ11A	3.0SMCJ11CA	HDZ	IDZ	11	12.2	13.5	1	18.2	164.8	1	50
3.0SMCJ12A	3.0SMCJ12CA	HEE	IEE	12	13.3	14.7	1	19.9	150.8	1	50
3.0SMCJ13A	3.0SMCJ13CA	HEG	IEG	13	14.4	15.9	1	21.5	139.5	1	50
3.0SMCJ14A	3.0SMCJ14CA	HEK	IEK	14	15.6	17.2	1	23.2	129.3	1	50
3.0SMCJ15A	3.0SMCJ15CA	HEM	IEM	15	16.7	18.5	1	24.4	123	1	50
3.0SMCJ16A	3.0SMCJ16CA	HEP	IEP	16	17.8	19.7	1	26	115.4	1	50
3.0SMCJ17A	3.0SMCJ17CA	HER	IER	17	18.9	20.9	1	27.6	108.7	1	50
3.0SMCJ18A	3.0SMCJ18CA	HET	IET	18	20	22.1	1	29.2	102.7	1	50
3.0SMCJ20A	3.0SMCJ20CA	HEV	IEV	20	22.2	24.5	1	32.4	92.6	1	50
3.0SMCJ22A	3.0SMCJ22CA	HEX	IEX	22	24.4	26.9	1	35.5	84.5	1	50
3.0SMCJ24A	3.0SMCJ24CA	HEZ	IEZ	24	26.7	29.5	1	38.9	77.1	1	50
3.0SMCJ26A	3.0SMCJ26CA	HFE	IFE	26	28.9	31.9	1	42.1	71.3	1	50
3.0SMCJ28A	3.0SMCJ28CA	HFG	IFG	28	31.1	34.4	1	45.4	66.1	1	50
3.0SMCJ30A	3.0SMCJ30CA	HFK	IFK	30	33.3	36.8	1	48.4	62	1	50
3.0SMCJ33A	3.0SMCJ33CA	HFM	IFM	33	36.7	40.6	1	53.3	56.3	1	50
3.0SMCJ36A	3.0SMCJ36CA	HFP	IFP	36	40	44.2	1	58.1	51.6	1	50
3.0SMCJ40A	3.0SMCJ40CA	HFR	IFR	40	44.4	49.1	1	64.5	46.5	1	50
3.0SMCJ43A	3.0SMCJ43CA	HFT	IFT	43	47.8	52.8	1	69.4	43.2	1	50
3.0SMCJ45A	3.0SMCJ45CA	HFV	IFV	45	50	55.3	1	72.7	41.3	1	50
3.0SMCJ48A	3.0SMCJ48CA	HFX	IFX	48	53.3	58.9	1	77.4	38.8	1	50
3.0SMCJ51A	3.0SMCJ51CA	HFZ	IFZ	51	56.7	62.7	1	82.4	36.4	1	50

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		MAR	/ICE KING DE	REVER SE STAND-	BREAKD OWN VOLTAG	BREAKDO WN	TEST	MAXMU M CLAMPI	PEAK PULS	REVE RSE	REVERSE LEAKAGE
UNI-POLAR	BI-POLAR	UNI	Ы	OFF VOLTA GE VRWM (V)	E VBR (V) MIN. @I _T	VOLTAGE VBR (V) MAX. @I _T	ENT IT(MA)	NG VOLTAG E @Ipp Vc(V)	E CURR ENT Ipp(A)	LEAK AGE @V _{RWM} I _R (uA)	@V _{RWM} T _J =150°C I _R (uA)
3.0SMCJ54A	3.0SMCJ54CA	HGE	IGE	54	60	66.3	1	87.1	34.4	1	50
3.0SMCJ58A	3.0SMCJ58CA	HGG	IGG	58	64.4	71.2	1	93.6	32.1	1	50
3.0SMCJ60A	3.0SMCJ60CA	HGK	IGK	60	66.7	73.7	1	96.8	31	1	50
3.0SMCJ64A	3.0SMCJ64CA	HGM	IGM	64	71.1	78.6	1	103	29.1	1	50
3.0SMCJ70A	3.0SMCJ70CA	HGP	IGP	70	77.8	86	1	113	26.5	1	50
3.0SMCJ75A	3.0SMCJ75CA	HGR	IGR	75	83.3	92.1	1	121	24.8	1	50
3.0SMCJ78A	3.0SMCJ78CA	HGT	IGT	78	86.7	95.8	1	126	23.8	1	50
3.0SMCJ85A	3.0SMCJ85CA	HGV	IGV	85	94.4	104	1	137	21.9	1	50
3.0SMCJ90A	3.0SMCJ90CA	HGX	IGX	90	100	111	1	146	20.5	1	50
3.0SMCJ100A	3.0SMCJ100CA	HGZ	IGZ	100	111	123	1	162	18.5	1	50
3.0SMCJ110A	3.0SMCJ110CA	HHE	IHE	110	122	135	1	177	16.9	1	50
3.0SMCJ120A	3.0SMCJ120CA	HHG	DHG	120	133	147	1	193	15.5	1	50
3.0SMCJ130A	3.0SMCJ130CA	ННК	IHK	130	144	159	1	209	14.4	1	50
3.0SMCJ150A	3.0SMCJ150CA	HHM	IHM	150	167	185	1	243	12.3	1	50
3.0SMCJ160A	3.0SMCJ160CA	HHP	IHP	160	178	197	1	259	11.6	1	50
3.0SMCJ170A	3.0SMCJ170CA	HHR	IHR	170	189	209	1	275	10.9	1	50

For bidirectional type having V_{RWM} of 10 volts and less, the IR limit is double. For parts without A , the VBR is ± 10%



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Ratings and Characteristics Curves



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Ordering Information

Device	Package	Plating	Shipping
3.0SMCJ5.0A THRU 3.0SMCJ170A	SMC (Pb-Free)	Pure Sn	3000pcs / reel
3.0SMCJ5.0ATR THRU 3.0SMCJ170ATR	SMC (Pb-Free)	Pure Sn	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Mechanical Dimensions SMC



HDE Where XXXXX is YYWWL XXXXXX HE YY 3.0SMCJ

SMCJ5.0/	W' L	
IDE XXXXXX	Ъ	Αι

3.0SMCJ5.0CA

Marking Diagram

DE/IDE	= Marking code
Y	= Year
W	= Week
	= Lot Number

utions: Molding resin Epoxy resin UL:94V-0

SYMBOL **Millimeters** Inches Min. Max. Min. Max. 6.22 0.220 0.245 А 5.59 В 6.60 7.11 0.260 0.280 С 2.75 3.25 0.108 0.128 0.305 D 0.152 0.006 0.012 7.75 8.25 0.325 Е 0.305 F 2.00 2.95 0.079 0.116 G 0.051 0.203 0.002 0.008 Н 0.76 1.60 0.030 0.063

Carrier Tape Specification SMC



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SYMBOL	Millimeters				
	Min.	Max.			
А	5.90	6.10			
В	8.20	8.40			
С	2.40	2.60			
d	1.40	1.60			
E	1.40	1.60			
F	7.60	7.70			
Р	7.90	8.10			
P0	3.90	4.10			
P1	3.90	4.10			
Т	-	0.600			
W	15.80	16.20			

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